NSN 5961-00-007-3857

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-007-3857 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches Overall Diameter: Between 0.470 inches and 0.500 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-66 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector to emitter, sustained and 100.0 breakdown voltage, collector-to-base, emitter open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 25.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No